
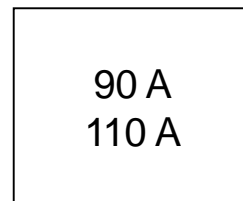


THREE PHASE BRIDGE

Power Modules

Features

- Package fully compatible with the industry standard INT-A-pak power modules series
- High thermal conductivity package, electrically insulated case
- Outstanding number of power encapsulated components
- Excellent power volume ratio, outline for easy connections to power transistor and IGBT modules
- 4000 V_{RMS} isolating voltage
- UL E78996 approved 



Description

A range of extremely compact, encapsulated three phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and heavy duty applications.

Major Ratings and Characteristics

Parameters	90MT.KB	110MT.KB	Units
I_O	90 (120)	110 (150)	A
@ T_C	90 (61)	90 (57)	°C
I_{FSM}	770	950	A
@ 50Hz	810	1000	A
@ 60Hz	3000	4500	A ² s
I^2t	2700	4100	A ² s
@ 50Hz	30000	45000	A ² √s
@ 60Hz			
V_{RRM} range	800 to 1600		V
T_{STG} range	-40 to 150		°C
T_J range	-40 to 150		°C

90-110MT..KB Series

Bulletin I27501 rev. A 05/03

International
IRF Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

Type number	Voltage Code	V_{RRM} , maximum repetitive peak reverse voltage V	V_{RSM} , maximum non-repetitive peak rev. voltage V	I_{RRM} max. @ T_J max. mA
90-110MT..KB	80	800	900	10
	100	1000	1100	
	120	1200	1300	
	140	1400	1500	
	160	1600	1700	

Forward Conduction

Parameter	90MT.KB	110MT.KB	Units	Conditions
I_O Maximum DC output current @ Case temperature	90 (120)	110 (150)	A	120° Rect conduction angle
	90 (61)	90 (57)	°C	
I_{FSM} Maximum peak, one-cycle forward, non-repetitive surge current	770	950	A	t = 10ms No voltage
	810	1000		t = 8.3ms reapplied
	650	800		t = 10ms 100% V_{RRM}
	680	840		t = 8.3ms reapplied
I^2t Maximum I^2t for fusing	3000	4500	A ² s	t = 10ms No voltage
	2700	4100		t = 8.3ms reapplied
	2100	3200		t = 10ms 100% V_{RRM}
	1900	2900		t = 8.3ms reapplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	30000	45000	A ² √s	t = 0.1 to 10ms, no voltage reapplied
$V_{F(TO)1}$ Low level value of threshold voltage	0.89	0.81	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, @ T_J max.
$V_{F(TO)2}$ High level value of threshold voltage	1.05	0.99	V	$(I > \pi \times I_{F(AV)})$, @ T_J max.
r_{F1} Low level value of forward slope resistance	5.11	4.37	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$, @ T_J max.
r_{F2} High level value of forward slope resistance	4.64	4.64	mΩ	$(I > \pi \times I_{F(AV)})$, @ T_J max.
V_{FM} Maximum forward voltage drop	1.6	1.4	V	$I_{pk} = 150A$, $T_J = 25^\circ C$, $t_p = 400\mu s$ single junction
V_{INS} RMS isolation voltage	4000	4000	V	$T_J = 25^\circ C$, all terminal shorted f = 50Hz, t = 1s

Thermal and Mechanical Specifications

Parameter	90MT.KB	110MT.KB	Units	Conditions
T_J Max. junction operating temperature range	-40 to 150		°C	
T_{stg} Max. storage temperature range	-40 to 150		°C	
R_{thJC} Max. thermal resistance, junction to case	0.21	0.18	K/W	DC operation per module
	1.26	1.07		DC operation per junction
	0.25	0.21		120° Rect conduction angle per module
	1.47	1.25		120° Rect conduction angle per junction
R_{thCS} Max. thermal resistance, case to heatsink	0.03		K/W	Per module Mounting surface smooth, flat and greased
T Mounting torque $\pm 10\%$	to heatsink	4 to 6	Nm	A mounting compound is recommended and the torque should be rechecked after a period of 3 hours to allow for the spread of the compound. Lubricated threads.
	to terminal	3 to 4		
wt Approximate weight	176		g	

Ordering Information Table

Device Code					
11	0	MT	160	K	B
①	②	③	④	⑤	

1 - Current rating code: 9 = 90 A (Avg)
11 = 110 A (Avg)

2 - Three phase diodes bridge

3 - Essential part number

4 - Voltage code: Code x 10 = V_{RRM} (See Voltage Ratings Table)

5 - Generation II

Outline Table (without optional barriers)

Screws M5 x 0.8 Length 10

All dimensions in millimeters (inches)

NOTE: To order the Optional Hardware see Bulletin I27900

90-110MT..KB Series

Bulletin I27501 rev. A 05/03

Outline Table (with optional barriers)

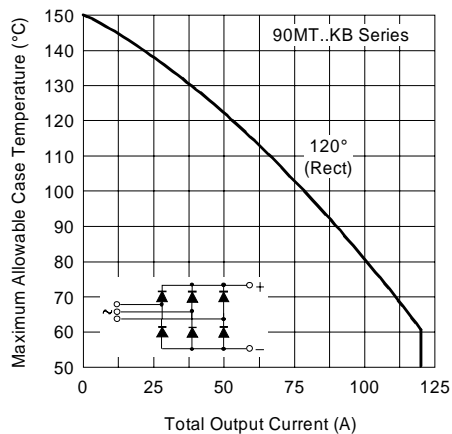
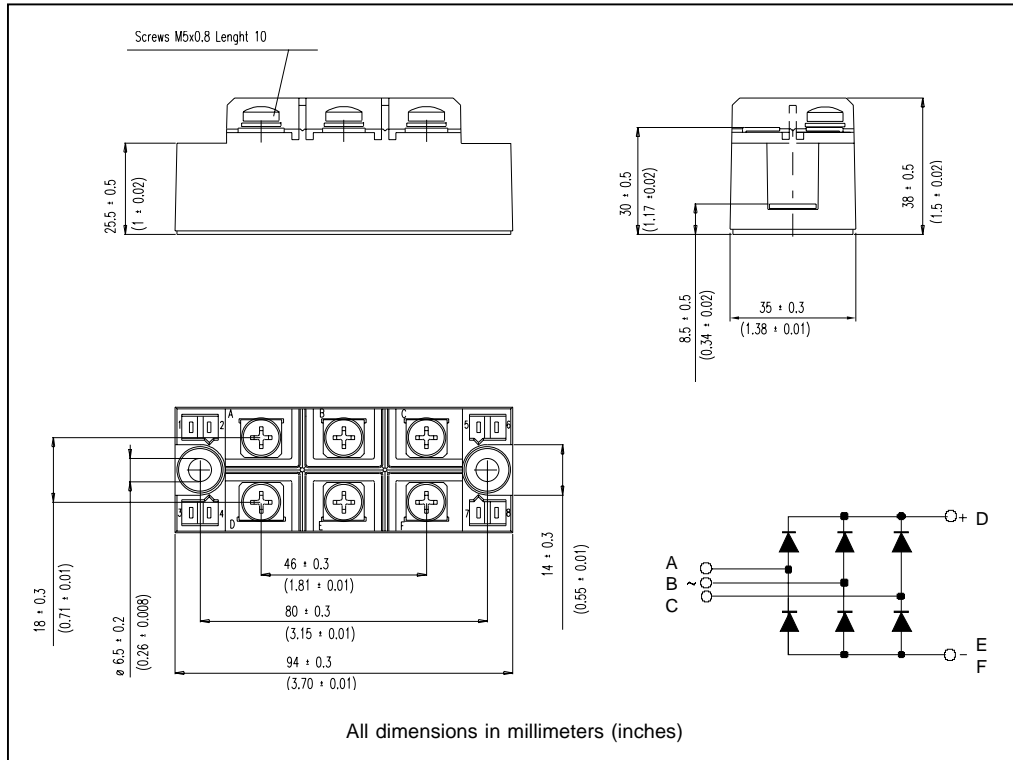


Fig. 1 - Current Ratings Characteristics

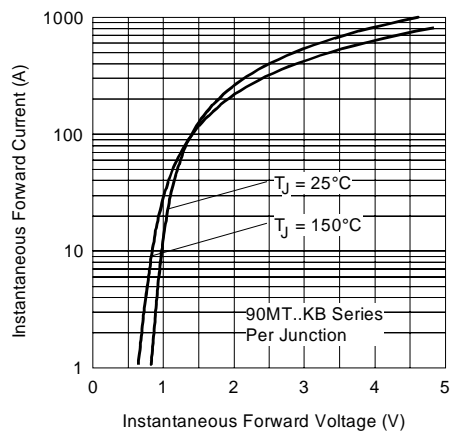


Fig. 2 - Forward Voltage Drop Characteristics